# MOSPEC

# **Switchmode Dual Ultrafast Power Rectifiers**

... Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- \* High Surge Capacity
- \* Low Power Loss, High efficiency
- \* Glass Passivated chip junctions
- \* 150 °C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction
- \* Low Forward Voltage , High Current Capability
  \* High-Switching Speed 35 Nanosecond Recovery Time
- \* Plastic Material used Carries Underwriters Laboratory

## **MAXIMUM RATINGS**

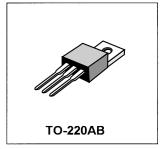
Characteristic	Symbol	U16C				Unit
		05	10	15	20	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	150	200	٧
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	105	140	٧
Average Rectifier Forward Current Per Leg T <sub>c</sub> =125°C Per Total Device	I <sub>F(AV)</sub>	8.0 16			А	
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz, T <sub>C</sub> =125°C)	İ <sub>FM</sub>	16			Α	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware,single phase,60Hz)	  FSM	150			А	
Operating and Storage Junction Temperature Range	T <sub>j</sub> , T <sub>stg</sub>	- 65 to + 150			°C	

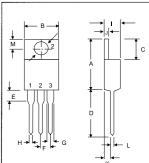
### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	U16C				Unit
		05	10	15	20	
Maximum Instantaneous Forward Voltage ( $I_F$ =8.0 Amp, $T_c$ = 25 $^{\rm o}$ C) ( $I_F$ =8.0 Amp, $T_c$ = 100 $^{\rm o}$ C)	V <sub>F</sub>	0.975 0.880			V	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_c = 25$ °C) (Rated DC Voltage, $T_c = 125$ °C)	I <sub>R</sub>	10 500			uA	
Reverse Recovery Time ( $I_F = 0.5 \text{ A}, I_R = 1.0, I_{rr} = 0.25 \text{ A}$ )	T <sub>rr</sub>	35		ns		
Typical Junction Capacitance ( Reverse Voltage of 4 volts & f=1 MHz)	C <sub>P</sub>	120		pF		

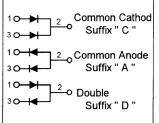
#### **ULTRA FAST RECTIFIERS**

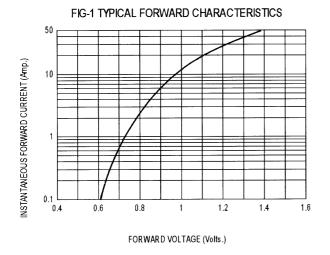
**16 AMPERES** 50 -- 200 VOLTS

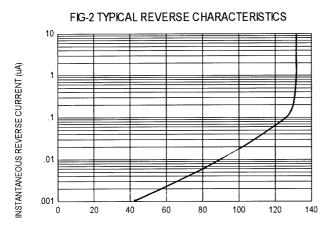


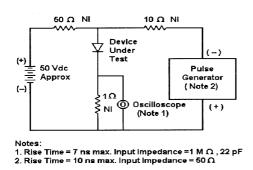


	MILLMETERS			
DIM	MIN	MAX		
Α	14.68	15.32		
В	9.78	10.42		
С	6.01	6.52		
D	13.06	14.62		
Ε	3.57	4.07		
F	2.42	2.66		
G	1.12	1.36		
Н	0.72	0.96		
ı	4.22	4.98		
J	1.14	1.36		
K	2.20	2.97		
L	0.33	0.55		
М	2.48	2.98		
0	3.70	3.90		









PERCENT OF PEAK REVERSE VOLTAGE(%)

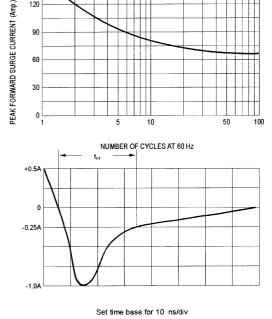


FIG-3 FORWARD CURRENT DERATING CURVE

CASE TEMPERATURE (  $^{0}$  C ) FIG-4 TYPICAL JUNCTION CAPACITANCE

REVERSE VOLTAGE (Volts.) FIG-5 PEAK FORWARD SURGE CURRENT

50

100

AVERAGE FORWARD RECTIFIED CURRENT (Amp.)

12

500

100

120

90

30

JUNCTION CAPACITANCE (pF)

Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram